Thermo-cyclically operated metal oxide gas sensor arrays for analysis of dissolved volatile organic compounds in fermentation processes: Part I – Morphology aspects of the sensing behavior



Binayak Ojha, Margarita Aleksandrova, Matthias Schwotzer, Matthias Franzreb, Heinz Kohler

PII:	S2214-1804(23)00010-7
DOI:	https://doi.org/10.1016/j.sbsr.2023.100558
Reference:	SBSR 100558
To appear in:	Sensing and Bio-Sensing Research
Received date:	23 January 2023
Revised date:	20 March 2023
Accepted date:	24 March 2023

Please cite this article as: B. Ojha, M. Aleksandrova, M. Schwotzer, et al., Thermocyclically operated metal oxide gas sensor arrays for analysis of dissolved volatile organic compounds in fermentation processes: Part I – Morphology aspects of the sensing behavior, *Sensing and Bio-Sensing Research* (2023), https://doi.org/10.1016/ j.sbsr.2023.100558

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compounds in fermentation processes: Part I – Morphology aspects of the sensing behavior

Binayak Ojha^{1,*}, Margarita Aleksandrova¹, Matthias Schwotzer², Matthias Franzreb² and Heinz Kohler^{1,*}

¹Institute for Sensor and Information Systems (ISIS), Karlsruhe University of Applied Sciences, Moltkestr. 30, D-76133 Karlsruhe, Germany

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²Institute of Functional Interfaces (IFG), Karlsruhe Institute of Technology (KIT), Hermann-von-Helmholtz-Platz 1, D-76344 Eggenstein-Leopoldshafen, Karlsruhe, Germany

*Corresponding authors.

E-mail addresses: binayak.ojha@h-ka.de (B. Ojha), heinz.kohler@h-ka.de (H. Kohler)

Abstract

For a comparative study of the gas sensing performance to dissolved volatile organic compounds (VOCs), the SnO₂-powders have been prepared using two different fabrication routes; the flame-spray-pyrolysis (FSP) and the sol-gel (SG) route; and were admixed with the same additive-powders (alumina, YSZ, and NASICON). The morphology of the two different SnO₂/additive families were investigated by ESEM analysis and Energy-dispersive X-Ray Spectroscopy (EDS). Both SnO₂/additive material families were separately deposited as thick-film-layers on two four-fold sensor-chips which were simultaneously thermocyclically operated in a measurement cell combined with a carrier gas probe, which enables sensing tests with evaporated VOCs (acetic acid, propionic acid, ethanol, acetone) dissolved in water. The resulting Conductance-over-Time-Profiles (CTPs) highlight better sensitivities of most of the FSP-layers to all the analytes compared to the .G-prepared layers. Furthermore, the CTP shapes of the FSP layers show clearly enhanced specificity representing the indiviviral malyte components. This was interpreted to be the consequence of the extremely fine, scarcely agglomerated grain incombology of FSP-prepared powders and their very narrow grain size distribution which provide better conditions for enhanced gas specific surface reactions. Results promise a better chemical analysis capability of dissolved VOCs by numerical analysis or the CTP of FSP-prepared gas sensitive layers.

Keywords: metal oxide, gas sensor, thermo-cyclic operation fla. ve-spray pyrolysis, VOC analysis

1 Introduction

Chemoresisitive metal oxide gas sensors (MOGs) are well established devices which are discussed for use in many applications like early fire detection in electrical installations [1], flue gas analysis in wood combustion [2], food-quality control [3], public and household security, environmental monitoring, industrial emission control [4] and even in biomedical applications like breath analysis [5,6]. However, this requires clear improvement of the reproducibility of their sensing performance and therefore several steps especially in material science have been done in the last decades to produce well reproducible gas sensing layers with well-defined morphology provided by advanced methods of nanotechnology. Intensive research was focused on the influence of additives in nanoscaled distribution and of the grain size of the matrix material (mostly SnO₂ or ZnO) on the gas sensitivity in general and how sensitivity to specific gas components of interest can be cultivated by those additives. The reader may get a more complete overview from the excellent review of N ri 1.1, in which several review articles are cited. Meanwhile, several million devices are applied worldwide per year [8] are to their high sensitivity to a large number of oxidizable or reducible gas components [9,10], their rather good long-ter. stability and simple operation at relatively low costs. However, in spite of this high level of knowledge about the sensing effects, there are still enormous research activities running to gain a deeper understanding of the surface processes at cifferent material morphologies which control the sensor behavior [11]. Simultaneously, there has been continuous evolution on advanced sensor fabrication processes to make this type of sensor also available as microstructure systems integrated in picroelectronic devices [12] following the idea to utilize further improved sensor chips for more sophisticated tasks in the 1. d of gas analysis [3]. The latter aspect needs to initiate further research efforts particularly to improve understanding of the influence of the morphology of the gas sensitive metal oxide materials [13], the role of additives on the sensitivity in porteral, on specific sensitivities desired for special applications and on long-term stability.

Another important aspect concerning utilization of MOGs for analytical purposes is, how to extract as much analytical information as possible from the analyte by use of those devices. MOGs are usually operated at fixed temperature in the range of 300 °C \leq T \leq 450 °C. Despite careful selection of additives to attain specific sensitivities, for many applications isothermally operated MOGs lack sufficient discriminating capability to interfering gas components and, as a fact, do not enable gas component identification. Therefore, a single sensor element is considered unsuitable for chemical analysis. In the past, different signal analysis approaches like principle component analysis (PCA) [14,15], artificial neural networks [15–18], multi component analysis (MCA) [19] and pattern recognition methods [19,20] have been developed in order to improve the gas identification capability of isothermally operated MOG-sensor arrays.

mode [21–23], i.e. to vary the operation temperature thermo-cyclically. This operation mode was originally introduced about 25 years ago [24] following the idea that resistance change of the MO-layer is based on gas surface reactions which may be roughly described by the combination of different processes like surface adsorption of the gas molecules, surface chemical reactions with already adsorbed negatively charged oxygen states followed by electron delocalization and desorption of the reaction products. The gas adsorption equilibria and the rates of all these surface processes depend specifically on the reaction process with the individual target molecule and are all specifically and mostly strongly dependent on the temperature. By periodic variation of the sensor temperature the rates of these surface processes are modified periodically. Therefore, thermo-cyclic variation in a triangular shape in time and simultaneous sampling of the conductance results in a molecular specific conductance dependent on temperature but measured over time. The corresponding "conductan p fingerprint" represents the specific target molecule interaction with the individual gas sensitive material and adsorb d oxygen species $(O_{2ads}^2, O_{ads}^2, O_{ads}^2)$ vs. temperature but measured as a conductance-over-time profile (CTP) [25]. 'Ic vev r, only if the rate of temperature variation of the sensor is slow enough compared to the kinetics of chemical response (tr. s includes diffusion rates in the porous layer as well as adsorption/desorption and reaction rates), the target gas specific CiP represents a quasi-steady state chemical response. In general, this target gas specific chemical response occurs due to do for ent processes happening at the sensor surface: (1) type of adsorbed oxygen states ($O_{2 ads}^{-}$, O_{ads}^{-} , O_{ads}^{2-}) [26] whic. var es over the temperature range. (2) oxidation temperature of the analyte, (3) temperature variation rate, (4) layer thic. ness, grain size and morphology [27]. All these define the diffusion rate and reaction kinetics of gas species in the pores of the layer. In addition, (5) specific reactions at the electrode/metal oxide interfaces [26,28], and (6) specific reactions at u. a additive/metal oxide interface [21] have to be considered. It was shown that by the numerical analysis of the resulting target gas specific CTPs not only the molecular identification, but even a full analysis by quantitative determination of the fas c mponent concentrations is possible [29]. In addition to enhanced gas analysis capabilities, the periodic variation of the sensor temperature improves sensitivity [30,31] and can reduce long-term drift [32]. All these results confirmed that gas analysis capability of a single sensor can be clearly enhanced by non-isothermal operation, and furthermore the thermo-cyclic operation of an array of different, but well-selected gas sensitive materials is expected to promise even further substantial enhancement of the analytical capability [33].

This work was motivated by the idea to develop a single-chip fourfold array of extremely sensitive MOGs for early analysis of undesired volatile organic acids (VOAs) like acetic acid, propionic acid or butyric acid developing in biogas fermentation processes in presence of different cross sensitive gas components like CO, CH₄ and H₂. This issue needs special pre-treatment of the analyte and the analysis results will be reported in an upcoming paper. Different metal oxides, especially combinations of matrix oxides with different additives like Y doped SnO₂ [34], Y doped ZnO [35,36], Pr doped ZnO [37], Co doped LaFeO₃ [38], alumina admixed SnO₂ [30], YSZ admixed SnO₂ [30] and NASICON admixed SnO₂[30] were reported for their enhanced acetic

SnO₂ with 3D nanosheets [41] were published to have excellent acetic acid sensing properties. As a general result, it was found, that the sensing properties are clearly influenced by the choice of the additive and by the morphology of the sensitive layers as well.

In this paper, for the first time, the gas sensing characteristics of two simultaneously operated sensor arrays consisting of the same SnO₂/additive layers but differing by differently prepared tin oxide matrix materials were compared. The tin oxide powders were fabricated by (i) the classical sol-gel (SG) route, and (ii) a flame spray pyrolysis (FSP) technique, which leads to different morphologies as disclosed from investigations with an Environmental Scanning Electron Microscope (ESEM). From model gas exposure experiments with VOAs, whose development in biogas fermentation processes is undesired and continuous monitoring, of VOAs is still a loophole in process analysis, the authors expected new insight with respect to the analysis capability of those substances at thermo-cyclic operation of the sensor chips. So callec conductance-over-time-profiles (CTPs) of thermocyclically operated every chemoresistive gas sensitive layers were the individual shape of the CTPs with respect to the target VOC and (ii) the sensitivities of the layers and specificity of the CTP shapes dependent on the layer-morphology, are reported. The latter aspect is of fundamental importance for high and process monitoring of the VOCs by numerical analysis of the CTPs [21].

2 Methodology of the gas analysis concept

The concept of in-situ analysis of dissolved vocs in water by operation of a carrier gas probe with a thermo-cyclically operated MOG sensor array is illustrated with a sketchy drawing of the experimental setup in [21]. A constant carrier gas stream is lead in stainless steel gas permeation charrier covered by a gas permeable membrane (silicone rubber) which separates the carrier gas from the aqueous analy. Non-dissociatively dissolved VOC permeates through the gas permeable membrane from the liquid phase to the gas phase and is transported with the carrier gas to the measurement cell, complemented with the MOG sensor-array.

Regarding the functional dependency of the analyte concentration in the carrier gas, two aspects must be taken into consideration. First, the partial pressure (p) in the gas phase of physically, i.e., non-dissociatively dissolved VOC for low concentrations is proportional to its concentration (c) in the liquid phase according to Henry's law (eq. 1),

$$p = K_H.c$$

 K_H is the analyte specific Henry's law constant and p is the partial pressure of the analyte in the gas phase in thermodynamic equilibrium with the liquid phase (no gas flow). Indeed, p in the carrier gas is very low. It depends on the gas permeability of the membrane, on the contact time of the carrier gas with the membrane (carrier gas flow rate), and on the temperature.

(1)

concentration of the analyte in the carrier gas transported to the sensor is the carrier gas flow rate. As lower the flow rate is, as longer is the time for taking up the analyte by the carrier gas permeating across the silicon rubber membrane. Thus, relative concentration of the analyte would reach its maximum at thermodynamic equilibrium, i.e., when the carrier gas flow rate is zero. However, this is impracticable because there would be no gas transported to the sensor chip. Thus, to maximize the sensitivity, a compromise has to be found between high analyte concentration in the carrier gas (low flow rate) to produce high gas sensitivity, and enough analyte transported to the sensor chip, having in mind, that there is some considerable consumption of the analyte at the surface of the MOG by the reaction with (adsorbed) oxygen (Section 1). This aspect was studied in detail (Section 4.1) before the response of different metal oxide layers on various dissolved VOCs was investigated.

The sensor arrays were operated in a sensor cell at the thermo-cyclic mode at temperatures between 150(\pm 5) °C and 450(\pm 5) °C using a triangular heating voltage (Fig. 1a). The sensor measurement call provides holders for up to two sensor array chips, which can be exposed to analyte gases simultaneously. Generally, the CTFs of all the sensitive layers on sensor arrays together with the resistance of the Pt-meander microstructured on the coparide of the chip (Pt-temperature sensor, (Fig.4a) are recorded simultaneously. The Pt-meander resistance is transformed to the actual surface temperature (Fig. 1b) using calibration data experimentally determined in a temperature controlled tuite to react an advance.

For numerical analysis of the sensor response when elepsed to different VOC components (acetic acid, propionic acid, ethanol and acetone), the total absolute changes of the CTPs, i.e., *G-Go* were used, where *Go* is *Go(hum. air) i.e.*, the CTP measured in DI water at pH 7 and *G* is the CTP response measured in presence of the VOC-analyte dissolved in DI water at pH 3. The pH 3 condition makes sure that the VOAs are in the non-dissociated state which is a prerequisite of detection with this method.

The integral value $\sum (G-Go)$ represents the analyte concentration *c* in the DI water at pH 3 and can be fitted well by a power law (eq.2) [24,42,43], which could be u. ed for numerical quantitative chemical analysis in simple cases.

(2)

$$\Sigma(G - Go) = \alpha c^{\beta}$$

As will be discussed in Section 4.5, the pre-exponential factor α and the power law exponent β are primarily molecular specific constants [44] and are related to the individual surface reaction mechanism at a given temperature [45] as well as on the morphology of the sensing layer [46]. The sensing performance of individual sensing layers for different VOCs is compared in terms of the relative sensor response S. For thermo-cyclically operated MOGs this value had to be defined specifically (eq. 4 in [47]). In this paper this definition had to be applied to the specific issue of investigation (eq. 3). $G_x(VOC)$ is the conductance at a sampling point *x* at dissolved VOC concentration *c* at pH 3, Go_x is the conductance at the same sampling point *x* measured in presence of DI water at pH 7 and *n* is the total number of sampling points in one measurement cycle; in this case *n*=128.

To get a better overview about the distinctive features of the CTP-shapes, the CTPs were additionally plotted as normalized curves. Normalization was made by the conductance value at the highest temperature (Tmax) of a thermo-cycle. To take this value for normalization may give some impression of arbitrariness. However, it is a peculiar point of conductance at Tmax of thermo-cycle, i.e., at about 450 °C. At this point gas adsorption is mostly unfavorable, i.e., the surface should be mostly clean from adsorbed molecules. On the other hand, reaction kinetics is maximum. Having these behaviors in mind, the resulting normalized CTPs should show the CTP-features generated by surface processes at T<450 °C but related to the (residual) processes at the peak temperature.

3 Experimental

Pure SnO₂ powders of nanoscaled grain size were produced following two Liffer ant synthesis routes (Section. 3.1), (i) the sol-gel (SG) method and, (ii) the Flame-Spray-Pyrolysis (FSP) method. Each type of powder (SnO₂(SG), SnO₂(FSP)) was admixed with different additive powders, alumina (MZS-1, Martinswerk Gn bH), yttrium stabilized zirconia (YSZ) (TZ-8YS, Tosoh Corporation LTD) and NASICON (prepared by our own) by ball milling. Finally, all powders were transferred to printable pastes and deposited on pre-prepared chips (Section. 3.2) with a heat or on the reverse side and four inter-digitized electrodes (IDEs) on the top side to fabricate single-chip four-fold sensor-arc is thus, four-fold sensor chips of two different kinds were achieved, one with SnO₂(SG)/additive-layers and others with Sno₂(FSP)/additive layers. This means, both kinds of chips provide the same SnO₂/additive-combinations but differ by the kind of SnO₂-powder preparation, by the layer thickness and by limited reproducibility of the layer geometry achieved by micro-dispensing of the pastes.

3.1 Sensitive material synthesis and sensor a gabrication

The sol-gel synthesis route of ChO₂ is described in detail in [30,48]. Pure SnCl₄ (Sigma-Aldrich) was slowly dropped in deionized water. The obtained sol was transformed into a gel by addition of ammonia solution. After aging of the gel for 3 weeks it was washed for several times with deionized water and ethanol to get it almost free of the chloride ions. The gel was then stirred, dried and ground for 6 h at 200 rpm in zirconia vessels by ball milling. A fine pale yellow SnO₂ powder was obtained after pre-sintering at 450 °C for 5 h. The XRD diffractograms of those sol-gel prepared SnO₂ powders at 80 °C and 450 °C are shown in Fig. 2.

A very promising alternative route for preparation of extremely fine SnO₂ nanoparticles is the Flame-Spray-Pyrolysis (FSP) method, which is described in detail in [49]. In a recent review [50] the exceptional properties of those FSP prepared nanopowders are illustrated and the different technics of deposition on sensor element substrates by either drop coating and annealing of flame-made nanoparticles or by direct combustion chemical vapor or aerosol deposition are discussed and the

 $S = \frac{1}{2}$

liquid precursor (tin(II)-ethylhexanote) in the flame. The size of the nanoparticles is well controlled and depends on the Sn concentration in the precursor and the flame operation conditions. Further, very narrow particle size distributions can be achieved by this novel preparation route. In this work the SnO₂(FSP)-powder was provided by our partner (see acknowledgement). The "drop coating - route" was applied, i.e., the FSP-prepared nanopowders were admixed with additives as introduced above and then transferred to a paste (see Section 3.1.2), which was then deposited on pre-prepared chips with four inter-digitized electrodes (IDEs) by a micro-dispensing technique.

3.1.1 Choice of additive materials and preparation of NASICON

As already mentioned above, two sensor array chips were prepared for comparison of the sensor performance of $SnO_2(SG)/additive-layers$ with $SnO_2(FSP)/additive-layers$. This means, both chips cr...'st of the same $SnO_2/additive-combinations$ (pure SnO_2 , $SnO_2/Alumina$, SnO_2/YSZ , $SnO_2/NASICON$) but differ by the SnO_2 proparation routes. Commercial fine powders of alumina and YSZ are available (see above) and were used for preparation of the corresponding pastes for dispensing (see below). However, NASICON ($Na_{1+x} Zr_2Si_xP_{3-x}$, $0 \le x \le 3$), one of the most father sodium solid electrolytes with high sodium ionic conductivity [51] had to be prepared ourselves. The sodium content of the NASICON-framework structure [52,53] can be widely varied and the ionic conductivity achieves its maximum *relation* or even as cathode material for high-temperature solid state rechargeable batteries [55,56] and was discussed array good candidate for development of all solid-state gas sensor elements [57].

NASICON (Na₃Zr₂Si₂PO₁₂, x=2) was prepared following a well-known SG-route[58]. $ZrO(NO_3)_2 \cdot 8H_2O$ (Sigma-Aldrich), Na₃PO₄ (Sigma-Aldrich), Si(C₂H₅O)₄ (Sigma-Aldrich), and C₆H₈O₇·H₂O (Carl-Roth GmbH) were individually dissolved in DI water at a specific molar ratio (2:1, 1:1, 2:1, and 2:1), r_{spert} :vely. The silica sol was prepared by continuous admixing of Si(C₂H₅O)₄ and DI water at 1:100 volume ratio by continuous magnetic stirring for 2 hours at ambient conditions.

 Na_3PO_4 , $Si(C_2H_5O)_4$ and $C_6H_8O_7 H_2O$ solution were added to the silica sol one after the other. The resulting mixture was continuously stirred for 1 h at 50 °C under sealed conditions. The resulting sol was aged for 3 h at 20 °C and was calcinated at 80 °C resulting in a white powder. The powder was ground at 200 rpm for 1 h in zirconia vessels using a planetary ball mill. Afterwards, the powder was sintered at 800 °C for 2 h, at 900 °C for 3 h and at 1000 °C for 4 h successively and all samples were characterized by XRD (Fig. 3). The NASICON-structure was clearly indicated [59]. With increasing sintering temperature the reflections became sharper, i.e. crystallization proceeded, but all XRD diffractograms reveal also some small ZrO₂ impurity phase as also observed in several studies in the past [52,60].

By admixing pure SnO₂ powder with organic binder (DSSP 80 820-MD, Ferro GmbH) and terpineol (Carl-Roth GmbH) by ball milling (planetary ball mill (Fritsch GmbH, Idar-Oberstein, Germany) with two vessels and balls, both made of Zirconia-ceramics) for 2 h at 120 rpm, two different pastes were prepared for micro-dispensing using SG and FSP synthesized SnO₂ as starting powders, respectively. The resulting pastes were denoted as SnO₂(SG) and SnO₂(FSP). For preparation of the SnO₂/additive pastes, the SnO₂(SG) as well as the SnO₂(FSP) powder were first admixed with alumina, YSZ and NASICON(x=2) powders in a volume ratio of 4:1, respectively, by ball milling and then these mixed powders were transferred into pastes by admixing with organic binder and terpineol in the ball mill as just described above. The pastes were denoted as SnO₂(SG), SnO₂(SG), SnO₂(SG)/Alumina, SnO₂(SG)/YSZ, SnO₂(SG)/NASICON, SnO₂(FSP), SnO₂(FSP)/Alumina, SnO₂(FSP)/YSZ, and SnO₂(FSP)/NASICON.

3.2 Fabrication of four-fold MOG sensor array chips

The four-fold MOG sensor array chips (size: $4 \times 4 \text{ mm}^2$) comprise four ID : and a resistive Pt-temperature sensor at the top side and a Pt-heater at the reverse side (Fig. 4). They were prepared using ν sputtering, photolithography and plasma etching techniques [33]. Each Pt-IDE thin film structure consists of ten finger, with 50 µm in width and 50 µm distance to the neighboring fingers. The thin-film Pt-layer thickness is about 1 µm

On the first sensor array chip (Fig. 4e) four differ int basis, namely, SnO₂(SG), SnO₂(SG)/Alumina, SnO₂(SG)/YSZ, and SnO₂(SG)/NASICON were deposited on the Pt-IDEs in thick. "Im form employing a micro-dispensing technique (DOTLINER 06, Martin GmbH, Wessling, Germany). Similarly, on the record chip (Fig. 4d) SnO₂(FSP), SnO₂(FSP)/Alumina, SnO₂(FSP)/YSZ, and SnO₂(FSP)/NASICON were deposited. After disclosing the layers were subsequently dried and then sintered at 700 °C for 20 minutes. The sintered FSP-layers (Fig. 4d) and SG-layers (Fig. 4e) look clearly different. FSP-layers are highly transparent in comparison to SG-layers. There is also cap. difference in the layer thickness between FSP-layers and SG-layers (Fig. 7). Additionally, as will be discussed in and the ESEM analysis (Fig. 8 and Fig. 10) disclosed that the SG-layers have clearly bigger average particle size and are more densely packed in comparison to the highly porous FSP-layers which have extremely small average particle size. Both aspects are assumed to result in much smaller light scattering intensities of the FSP-layers which in turn may explain the differences in transparency.

Afterwards, both chips were mounted on TO-8 headers using a micro welding technique. Both 4-fold sensor array chips consist of the same SnO₂-additive combinations but differ by the SnO₂ preparation routes (SG and FSP) and this means, differ by the morphology (grain size and distribution) of the SnO₂ as well as by the mean layer thickness and the thickness profile shape (Fig. 4). The surface morphology of the different SnO₂/additive-layers was analyzed using an environmental scanning electron microscope (Quattro, Thermo Fisher Scientific) equipped with a field emission gun (FEG). Some grain compositional analysis

the layer thickness of different layers was studied using a confocal microscope (µsurf explorer, NanoFocus AG, Germany).

To investigate the influence of the layer thickness on the sensor response behavior, a third sensor chip with four sensitive $SnO_2(SG)$ - layers of different thickness was prepared (Fig. 4c). Generally, the thickness of the layer is determined by the pressure applied on the paste in the syringe, the viscosity of the paste, the inner diameter of the needle (110 µm) and the velocity of movement across the area to be covered. Layer thickness beyond the thickness of a mono-layer was achieved by repetitive dispensing on previously dispensed and dried layers at ambient conditions before sintering.

3.3 Gas sensing tests

The experimental setup for analysis of physically, this means non-dissociativel¹ dissolved VOCs in the aqueous liquid (18 °C) of a thermostated bioreactor complemented by a carrier gas probe (see also *in thodology of gas analysis*, Section 2) is illustrated in Fig. 5. A carrier gas flow is kept constant by a commercial mass fill w controller (MFC), the pH of the analyte is checked by a pH-sensor and homogeneity of the analyte is achieved by continuous stirring. The gaseous analyte as extracted from the liquid sample is led to the measurement cell consisting of two thermo-cyclically operated sensor arrays (SnO₂(SG)/additive-type and SnO₂ (FSP)/additive-type) using a \exists way magnetic valve. This valve allows to expose the sensor arrays alternatively to the sample gas or to dry synthetic and Continuous cycling of the chip-temperature between 150(±5) °C and 450(±5) °C was achieved by heating the chip with a triangular heating voltage generated from a Keysight 34970A data acquisition unit. Additionally, the same unit measures the 128 conductance sampling points per temperature cycle of each gas sensitive layer of both chips.

3.3.1 Optimization of measurement conduirns

As already stated in Section 2, tl e m asurement conditions with respect to the carrier gas flow rate and the temperature cycling period had to be experimentall estimated to optimize the response of such sensor chips. To make this optimization at representative conditions related to the upcoming experiments, two sensor array chips with four sensitive layers each were operated in the measurement cell simultaneously and CTPs of one of the layers, FSP prepared SnO₂(FSP)/1%Pd-layer [49], at exposure to 4% acetic acid dissolved in DI water at pH 3, were analyzed at a cycle-time of 3 min at different carrier gas flows (2.5, 5, 10 and 20 ml/min). In the next step, at constant carrier gas flow the dependency of the CTP on the temperature cycling period was investigated with the same sensitive layer but at cycling periods of 3 min, 15 min and 30 min. In this case, 2000 ppm acetic acid dissolved in DI water was used as the analyte.

The sensor array consisting of layers with different thickness of $SnO_2(SG)$ (5 µm, 9.4 µm, and 18.2 µm) was exposed to different concentrations of acetic acid (500 ppm, 1000 ppm, and 2000 ppm) dissolved in DI water at pH 3 by use of the setup as described in Section 3.3. The measurements were performed at the optimal carrier gas flow rate of 5 ml/min and at the temperature cycling period of 15 min. The influence of the layer thickness on the CTP shape and the dependency of the CTP integrals on layer thickness is discussed in a representative manner in section 4.3 by illustration of the CTPs measured at 2000 ppm of acetic acid dissolved in DI water at pH 3 as an example (Fig. 12).

3.3.3 Studies of the gas sensing properties

Next, two sensor arrays consisting of SnO₂(FSP)/additive and SnO₂(SG)/additive layers respectively (Figs. 4d and 4e) were aged in the same measurement cell as introduced above at a constant flow (5 ml/r ..., o, synthetic air (about 2 ppm humidity) as provided in the gas bottle by the supplier (Linde GmbH) and at the optimal temperature cycling period of 15 min (see Section. 4.1). The aging of MO gas sensitive layers is necessary [61] to adjust the oxygen defect concentration, to stabilize the morphology (post sintering effects) and to desorb gaseous impurities before the measurements are started. After the conductance values of the sensitive layers did not further change sir, of ficantly in terms of a day (about 120 hours of continuous thermo-cyclic operation), the latest CTP (synth. air) was tables and solve at a constant of the sensitive.

Using the fully aged sensor arrays, all the following co. ⁴uctance measurements were performed at the optimal carrier gas flow rate of 5 ml/min and at the temperature cycling nericed of 15 min. The sensor responses were studied for different liquid phase concentrations of acetic acid, propionic acid, emanol and acetone dissolved in DI water at 18 °C, which are relevant for later studies of those compounds in biogas to mentation liquids (see upcoming paper (part II)). Liquid phase concentrations as used for the measurements and corresponding gaps phase concentrations at 25 °C as calculated using eq. 2 and K_H (Table 1) are given in Table 2. According to the vortuation in systems near ambient temperature [62] the values of K_H generally decrease exponentially with decreasing temperature. For example, calculated K_H (18 °C) for acetic acid is lower than K_H (25 °C) by a factor of 0.985. Thus, the real gas phase concentrations adjusted in the experiments are expected to be slightly lower than the values presented in Table 2. At each concentration step 12 CTPs were recorded and the last CTP was used for data illustration. **Table 1.** Henry constants (25 °C) of the VOCs used in the experiments.

voc	K _H / atm.kg.mol ⁻¹	Reference
Acetic acid	1.852×10 ⁻⁴	[63]
Propionic acid	1.785×10⁻⁴	[63]
Ethanol	5.263×10 ⁻³	[64]
Acetone	38.46×10 ⁻³	[64]

Acetic aci	Acetic acid / ppm		cid / ppm	Ethanol / ppm		Acetone	/ ppm	
Liquid phase	Gas phase	Liquid phase	Gas phase	Liquid phase	Gas phase	Liquid phase	Gas phase	
100	0.3	100	0.24	-	-	-	-	
200	0.6	200	0.48	-	-	-	-	
500	1.5	500	1.2	15	1.7	2.5	1.6	
1000	3	1000	2.4	30	3.4	5	3.2	
2000	6	2000	4.8	60	6.8	15	9.5	

4 Results and discussions

4.1 Studies to optimize measurement conditions

As already mentioned in Section 2, first the sensing conditions with respect to convier gas flow and the temperature cycling period had to be optimized before the performance of the analysis system could be investigated. As an example, Fig. 6a shows the CTP profiles of a SnO₂(FSP)/1%Pd-layer operated at a cycling period of 3 minutes at different carrier gas flow rates when 4% acetic acid was dissolved in DI water at pH 3.

The absolute conductance of the CTPs is lowest for 20 n. /min flow with a characteristic peak at ~335 °C (at 1 min). At a flow rate of 10 ml/min the CTP shows clearly higher abso. + conductance and a different CTP shape. A shoulder is observed at ~290 °C (0.8 min) and clear peaks at ~410 °C (1.3 min, while temperature rises and at ~360 °C (1.97 min) while temperature decreased. Further reduction of the flow rate to 5 nl min resulted in a further small increase of the absolute conductance maximum and the shoulder at heating phase s no more visible. Overall, the CTP shape is sharper in structure and the peaks are observed at ~410 °C (1.35 min) and ~ 380 °C (. 1.88 min). Further decrease of the flow rate to 2.5 ml/min resulted in a clearly lower absolute conductance with requee CTP features. From these results, it was clear that we must choose between 10 ml/min and 5 ml/min flow rate. However, these measurements were made for 4% acetic acid dissolved in DI water which is much higher than practical requirements considering the measurements of dissolved organic acids in fermentation processes. In all the upcoming experiments the carrier gas probe was operated at a flow rate of 5 ml/min to enable elongated contact of the carrier gas with the gas permeable membrane for optimization of the sensitivity.

At 5 ml/min carrier gas flow rate, the influence of the temperature cycling period on the CTP-integral and shape had to be further investigated. In Fig. 6b CTP profiles of SnO₂(FSP)/1%Pd operated at different cycle times while exposed to 2000 ppm acetic acid dissolved in DI water are given vs. the sampling points (n=128) which allows the comparison of the resulting CTPfeatures on a common time-base. The CTPs show clearly different absolute conductance and CTP features depending on the temperature rate. For 3 min cycling period, the absolute conductance is the lowest with characteristic peak at ~388 °C (t=0.4) and at ~325 °C (t=0.7). With increased cycling period to 15 min and 30 min, an additional shoulder is observed while heating and and 30 min, there is no difference in absolute conductance as well as in CTP features while temperature is decreased. However, while temperature is rising, CTP shape is broader, and the profile shoulder is a little bit better visible at the 30 min cycling period compared with the profile at 15 min. But the differences are not substantial, therefore the 15 min cycling period is used for all further measurements.

4.2 Layer thickness and morphology of the sensitive layers

The topographic image and the average thickness profiles of individual sensitive layers sampled with a confocal microscope are illustrated in Fig. 7. The thickness of the layers is not measured homogeneous. Moreover, each layer shows a laterally different thickness profile and, as desired, varies in absolute thickness. Moreover, the SnO₂(FSP)/additive-layers are typically prepared clearly thinner than the SnO₂(SG)/additive-layers. This has to be consiriered when comparing the CTPs and response behaviors.

Different morphologies by different routes of preparation: For the L^{FM} and EDS analysis, special sample-layers were coated with 3 nm thick gold layer. The ESEM-images of the surface morphologies of SnO₂(FSP) and of the SnO₂(FSP)/additive-layers are displayed in Fig. 8. The grain size of the SnO₂(FSP)-layer seems to be very homogeneous and the grain diameter is estimated to about 15 nm. Clear influence of the additive on the nO_2 grain size is not evident. From the ESEM images and the EDS analyses (Fig. 9a-9c) it is obvious, that the additive graine are not homogenously distributed in the SnO₂(FSP) matrix. This was investigated by EDS point analysis at different frees of the samples. By the EDS-spectra the additive-grains could be rather well localized. They exhibit a wide distribution or grain size (up to about 3 μ m) and are clearly larger compared to the SnO₂(FSP) grains. This is especially the case for the SnO₂($n^{-}P$)/NASICON-layer. The NASICON-grains were confirmed by EDS analysis in Area-1 and Area-2 (Fig. 9c) by strong peaks of Na, C, and Zr. In the SnO₂(FSP)/Alumina-layer the alumina was confirmed in Area-1 and Area-2 (Fig. 9a) by high peaks of an minum in the EDS analysis spectra. Similarly, in the SnO₂(FSP)/YSZ-layer (Fig. 9b) YSZ was localized in Area-3 as indicated clearly by additional peaks of Zr, Y close to the Au-peak of the EDS spectra. However, the analysis of Area-1 is different. No significant YSZ-signal (Zr and Y peak) was found.

Similarly, in Fig. 10, the morphology of SnO₂(SG) and of different SnO₂(SG)/additive-layers is illustrated. The SnO₂(SG) matrix consists of crystalline grains with a wide distribution of block sizes and homogenously distributed fine grains. At higher magnification (inset) the big SnO₂-blocks show a sub-structure of compactly packed nanosized particles with diameters smaller than 20 nm. This means the size of the sub-grains is in the same range than that of the grains obtained by the FSP-route (Fig. 8). However, on the SG-route the nano-grains seem preferably to crystallize to bigger crystalline blocks. This effect seems to be hindered by the FSP preparation technique. In contrast to the SnO₂(FSP)/additive layers, in SnO₂(SG)/additive-layers there are SnO₂ grain blocks with size comparable to the grain size of the additives (Fig. 11). This is especially the case for the

aks of

Na, Si as well as by Zr peaks observed for Area-1 (darker grain). Other brighter regions such as, Area-2 and Area-3 clearly represent the SnO₂. In case of SnO₂(SG)/Alumina layers (Fig. 11a), average grain size of tin oxide is obviously bigger than alumina as localized in Area-1 (SnO₂-grain) whereas, Area-2 and Area-3 clearly confirm the presence of alumina by strong Al peaks in the EDS spectra. Similarly, YSZ also seems to have smaller average grain size compared to SnO₂(SG) but appears to be more homogenously distributed in SnO₂(SG) matrix compared to other additives which is confirmed by the presence of the Zr, Y - peak in EDS analysis of all three areas analyzed (Fig. 11b). The difference in morphology may change the electronic interaction scenario of the additives with the tin oxide grains and may take different influence on the gas sensing properties [30].

4.3 Influence of the layer thickness on the CTP shape

The CTPs of SnO₂(SG) with average thickness of 5 μm, 9.4 μm and 18.2 μm, espectively (Fig. 7a) at exposure to 2000 ppm acetic acid are visualized in Fig 12a. Despite of the differences in the absolute this mess and conductance change, mainly in the heating phase of the cycle, the specific conductance peaks occurring with temperature are well reproducible (no peak shift) in all the layers, while the relative peak height is different for different layers. This result indicates that the reactions of the target gas with the adsorbed oxygen states (Section 1) are the same in al t'e 'ayers, but with different rate. As already mentioned in Section 1, a porous thick film tin oxide layer covering the underlying) Pt-IDE has to be considered as a chemical reactor with different reaction zones from the top to the metal electrode microstructured on the substrate (outer geom. surface, inner pore surface and electrode/metal oxide - interface, ret illustration in [33]) which all provide different (catalytical) reaction conditions. Thus, different (electric) contributio is to the overall sensing behavior have to be considered, measured as a change of resistance between the IDE-fingers. As the brough the tin oxide layer, a fraction of incident gas is consumed by each of the reaction zones and therefore the fraction of the target gas molecules reaching the lowest zone (electrode/metal oxide - interface) depends on the uffusion and reaction conditions (kind of additive, layer porosity and temperature). In other words, depending on the temperature of the sensitive layer, the layer thickness and its morphology, an effective concentration profile of the reactive gas components in the layer may be formed by which the distribution of sensitivity contributions over the layer thickness is given, which determines the overall sensitivity measured. Of course, this is only an idealized model of the real situation. As shown in Fig. 7, the thickness over a layer is not constant and the edge-effects are also not considered in this crude description. In addition, in case of thermo-cyclically operated tin oxide sensors, if the temperature change (typically) is not slow enough to reach steady state reaction situations, non-steady state situations in the different chemical reaction zones must be considered. This means, each reaction zone is exposed to a different target gas concentration at a time and, probably, different adsorbed oxygen surface state concentration resulting in different individual responses of the reaction zone. Despite these rather complicated reaction conditions, the response over layer thickness seems to be roughly linear (Fig. 12c). The normalized

CTPs (

on the

thinnest layer (5µm).

4.4 Conductance over time profiles for humidified air and four different VOCs dissolved in DI water

As mentioned in Section 3.2, both sensor arrays (Fig. 4d and 4e) were first aged in dry synthetic air before making measurements with dissolved VOCs in DI water. As an example, in Fig. 13 the CTPs measured for dry synthetic air (Go(dry air)) at the end of the aging process are illustrated together with the CTPs measured for DI water at pH 7(Go(hum air)) as sampled with the carrier gas probe in DI water in the experiment with model acetic acid.

As already introduced in Section 3.3, the concentration ranges of the VOCs chosen for investigation of the sensor responses for each analyte had to be individually set due to their specific Henry constants to enable comparable concentrations in the gas phase. The resulting CTPs as recorded for eight different sensitive layers (columnation of various concentrations of different VOCs (given in ppm by volume in DI water) like acetic acid, propionic acid, ethanol, and acetone (rows) are visualized in Fig. 14. Obviously, the tin oxide morphology, the additives and, of course, the analyte gas species, take clear influence on the CTP-shapes and the concentration of the analyte is well reflected in the CTP-integral as already reported in former investigations [33] and used for quantitative chemical analysis [29,65]. This memory, the individual surface reactions of the gas components on different sensitive layers are observed as VOC specific CTP tecture which are further illustrated in a normalized representation as shown in Fig. 15. Again, each CTP is normalized by the courductance value as recorded at the maximum temperature of the cycle.

The overview in Fig. 14 illustrates a clear cre. ⁴. The FSP-layers show specific and well pronounced CTP shapes with the individual gas component but dependent on the kind of additive. In comparison, the SG-layers show those individual featurecharacteristics as well, but typically less conounced. This can be, for instance, very well demonstrated, if the CTPs of SnO₂(FSP)/Al₂O₃ are compared with those of SnO₂(SG)/Al₂O₃ for all four analytes investigated. The individuality of the CTPs dependent on the target gas in case of the SnO₂(FSP)/Alumina – layer is clearly illustrated for all four components (Fig. 14). The CTP shapes of acetic and propionic acid are more similar, however, this is not surprising, because these are molecules with the same functional reaction groups. In contradiction, the CTPs of the SnO₂(SG)/Alumina – layer sampled at exposure to propionic acid, ethanol or acetone, i.e., of molecules with different functional reaction groups, are rather similar in shape and not very different from the shape of a CTP of a pure semiconductor vs. temperature, which is expected to be simply exponential. This means, that those profiles do only to some limited extent represent individual surface reactions of the target gas with the adsorbed oxygen states [33] at specific reaction temperatures. In addition, it is a remarkable fact, that nearly all FSP-prepared layers show a clearly higher dependency of G-Go on the target gas concentrations compared with the SG-prepared layers (Fig. 14). An exception are the pure SnO₂-layers where this difference in sensitivity was only observed at propionic acid exposure.

g. 15).

Obviously, the CTP-profiles are more or less constant with different concentrations of ethanol or acetone, whereas there is a clear decrease of the specific feature observed in the temperature range between about 300 °C and 400 °C with concentration of acetic acid as well as propionic acid. This behavior tells us, that in case of the carboxylic acids the reaction rate with the oxygen states is still increasing with both, temperature, and concentration, even at the highest temperature of a cycle. In case of ethanol and acetone, the reaction with the target gas seems to be more or less completed beyond some temperature below the maximum temperature Tmax=450 °C. This leads to the increase of the gas specific features with target gas concentration. The corresponding features in the same temperature range but in the second half of the CTP (decreasing temperature) are much less pronounced for all layers. This is a well-known fact [33,65] which is explained by differences in actual gas adsorption correlated with the direction of temperature change in accordance with well-established theory of gas adsorption [66–69].

4.5 Individuality of CTP shapes and comparison of sensor response to model (ase -

The individuality of the CTP-shapes at exposure to different analytes is ven better illustrated if the normalized CTP-curves from Fig. 15 are plotted into a common diagram. This was done in Fig. 10 which gives an overview about the gas specific CTPfeatures of all the SnO₂ - and SnO₂/additive – layers under inve tir_at on. The features of conductance-change by exposure of different target gas components are clearly different in hap position, and height (integral) and these "spectra" vary considerably with the kind of additive and morphology of the SnO₂-matrix. The height (integral) of the feature related to the individual target gas component is a measure of the placive response to this specific gas component at temperatures below Tmax. The position of the feature in the range (r c_{y} lic temperature variation and its shape represents the individual molecular reactions which are responsible for the conductance change [25]. These differences of the CTP-features related to the kind of target gas component and with respect to the individual SnO₂/additive-layer are clearly demonstrated in Fig. 16. Their peculiarity and reproducibility estimate the quality of chemical gas analysis by numerical analyses of these CTPs as e.g. demonstrated in [25,29]. In general, numerical analysis of the CTP of a sole layer already enables gas component analysis. The analysis quality depends mainly on the individuality of the CTP-features and on their reproducibility. Moreover, the use of a sensor array, namely simultaneous operation of different sensitive layers, provides multiple CTPs which further improves the gas identification quality by application of numerical multi-component analysis and pattern recognition methods [29]. The diagrams demonstrate, that the individuality of the CTP shapes measured on the SnO₂(FSP)/additive-layers related to different gas compounds is clearly better compared with the SnO₂(SG)/additive-layers. Correspondingly, enhanced gas analysis capability with the $SnO_2(FSP)$ /additive-layers can be expected.

Although the CTPs represent reaction states at different temperatures, their integral calculated according to eq. 2 (Fig. 14) vs.VOC concentration is well fitted by a power law. As an example, the integrals and regression curves for SnO₂(SG)/Alumina and

SnO₂(FSP)/Alumina – layer to acetic acid. This trend is confirmed as well by comparative measurements of the absolute gas response of several SnO₂/additive-layers to propionic acid (Fig. 17b). As an overview, the α - and β -values of all studied sensitive layers are given in Table 3. Different trends of the β -values for individual model VOC/layer – combinations are observed. One noticeable trend is the higher β -values for FSP-layers compared to corresponding SG-layers for nearly all the investigated VOCs, except the SnO₂(FSP)NASICON-propionic acid combination.

Test gas	Aceti	c acid	d Propionic acid		Ethanol		Acetone	
Sensitive layer	α	β	α	β	α	β	α	β
SnO ₂ (FSP)	0.75	0.86	2.83	0.85	9.75	0.92	46.32	0.81
SnO ₂ (FSP)/Alumina	1.42	0.88	7.26	0.80	44	0.73	239	0.65
SnO ₂ (FSP)/YSZ	1.31	0.85	5.73	0.84	19.6	0.86	77.6	0.81
SnO ₂ (FSP)/NASICION	1.26	0.86	15	0.57	16.3	0.79	114.8	0.63
SnO₂ (SG)	0.74	0.85	3	0.66	13.47	0.66	68.27	0.52
SnO₂ (SG)/Alumina	0.37	0.83	1.34	0.65	3.33	0.77	21.27	0.58
SnO ₂ (SG)/YSZ	0.68	0.82	2.43	0.68	13.75	0.66	84.02	u. ⁻ 0
SnO ₂ (SG)/NASICION	0.92	0.73	2.75	0.59	17.12	0.66	100.43	U. +ơ

Table 3: Estimated α , β values from regression analysis of \sum (G-Go) on exposure to different model VOCs

4.6 Comparison of gas response

The relative sensor response S (eqn. 3) of the uniferent SnO₂/additive-layers to the VOCs dissolved in DI water at pH 3 is illustrated for the individual concentrations of 1 JOU npm, 30 ppm and 5 ppm, respectively, in Fig. 18. As a trend, SnO₂(FSP) and SnO₂(FSP)/additive -layers show significantly nigher response to all the tested VOCs compared to the corresponding SG-layers. As an exception, the response of SnO₂(SG)/alumina to acetic acid is higher than the values of the SnO₂(FSP) and all the SnO₂(FSP)/additive-layers. In fact, a none onO₂(SG) and SnO₂(SG)/additive-layers SnO₂(SG)/Alumina shows the highest response to all the investigated VOCs. This phenomenon cannot be explained by the differences in layer thickness. As visualized in Fig. 7, SnO₂(SG)/Alumina was analyzed as the thinnest layer among SG-layers, however, it shows the highest response. This behavior does not follow the trend discussed in Section 4.3 (Fig. 12).

Furthermore, the response of the SnO₂(SG)/NASICON layer to acetic acid is the lowest although its layer thickness is the highest among the other SG-layers. It is even lower than that of the pure SnO₂(SG)-layer. Surprisingly, for FSP-layers this relation is reverse. The SnO₂(FSP)/NASICON – layer is relatively thin (about 5 μ m in average (Fig. 7)) but its response to acetic acid is the highest. In addition, the SnO₂(FSP)/NASICON – layer was measured to show the most pronounced CTP-features when exposed to the four different analytes. This property is very important with respect to the eligibility of those layers for gas analytical purposes and is only scored by the SnO₂(SG)/Alumina-layer (Fig. 13).

acetic acid, although the functional reaction group of acetic and propionic acid are the same, and they differ only by the molecular chain length. This difference in response is even more enhanced in case of the FSP-layers (Fig. 18). The response of SnO₂(FSP) is enhanced in relation to SnO₂(SG) by a factor of about 20. This substantial increase of the response behavior related to acetic acid was not observed when the layers were exposed to the non-acidic VOCs like ethanol and acetone. Further, in this context SnO₂(FSP)/NASICON seems to be an exception because the corresponding sensitivities to ethanol and acetone were measured to be clearly the highest.

In a first summary and for upcoming discussion, it must be pointed out, that for both acidic analytes considerable changes in gas response are observed when the SnO₂(SG) is admixed with additives. This is not the case for the non-acidic VOCs. In the most cases the sensitivities of the FSP-layers are clearly higher than those of the S-layers except for the SnO₂(SG)/Aluminalayer. This is highlighted in the large absolute response difference of roughly a factor of 20 of the SnO₂(SG)-layer vs. SnO₂(FSP)layer and of about a factor of three of the SnO₂(SG)/additive-layers vs. SnO₂, ⁱⁿCSP'/additive-layers when they are exposed with propionic acid. In this regard, also the SnO₂(FSP)/NASICON – layer must be discussed as an exception (see Section 4.6). Compared to SnO₂(FSP) and other SnO₂(FSP)/additive composites, Sn J₂(FSr)/NASICON showed lowest sensitivity to propionic acid but highest to acetic acid and to other VOCs.

5 Discussion on gas sensing

In a well-accepted model, the gas sensing merina ison of MOGs involves two main steps. First step is the chemisorption of the atmospheric oxygen ($O_{2 \ gas}$) by trapping or a c. two electrons from the conduction band and forming different adsorbed oxygen states ($O_{2 \ ads}^{-}$, O_{ads}^{-} , O_{ads}^{2-} , O_{ads}^{2-}) as illustrated in eqs. 4-7 [26]. The kind of negatively charged oxygen states depends on the temperature of the adsorbent [26]. The charge is balanced by the formation of an electron depletion layer in the surface near region of the porous metal oxide. The width of this electron depletion layer was defined by the Debye-length [50,70], which mainly depends on the temperature and the density of electron states (NE) of the bulk metal oxide. In this depletion layer the density of the mobile electrons, i.e., the electronic conductance is massively reduced and depends immediately on the density of the charged oxygen surface states.

$$O_{2 gas} \xrightarrow{T < 100 \,^{\circ}C} O_{2 ads} \tag{4}$$

$$O_{2 ads} + e^{-} \xrightarrow{T < 150 \,^{\circ}C} O_{2 ads}^{-} \tag{5}$$

$$O_{2 ads}^{-} + e^{-} \xrightarrow{200 \, ^{\circ}C < T < 400 \, ^{\circ}C} 2O_{ads}^{-}$$
(6)

$$O_{ads}^{-} + e^{-} \xrightarrow{T > 400 \,^{\circ}C} O_{ads}^{2-} \tag{7}$$

oxidation reaction with the adsorbed surface oxygen states. Examples of possible reaction mechanisms related to different VOCs are listed in eqs. 8-11 [71–74]. They represent total reactions which may have to be divided into several reaction steps, however, they have in common, that per molecule an individual number of formerly trapped electrons (oxygen surface states) are delocalized by the oxidation reaction. This means, after reaction with the VOC those electrons contribute now to the electron state density in the conduction band of the electron depletion layer (conductance increase) before they are localized again by a following surface oxygen adsorption process (conductance decrease). Overall, these processes when proceeding at environmental air conditions, form a steady state equilibrium situation dominated by the concentration of the target gas component, the temperature, the gas diffusion conditions in the porous layer and the real surface of the adsorbent. The latter is extensively given by the material morphology and porosity, which determine the output of surface reaction sites. This general model of surface reactions with adsorbed oxygen states was already introduced reactions ago e.g. by McAleer et al. [75]. The electric conductance variations by such surface chemical processes are echaracterized by a more or less increase in the conductance of the electron depletion layer of the porous MC layer in case of reactions with oxidizable target gas molecules. The difference in conductance related to the value without larget gas is defined as the gas response (eq. 3).

$CH_3COOH + 4O_{ads}^- \rightarrow 2CO_2 + 2H_2O + 4e^-$	(ò,
$CH_3CH_2C00H + 70_{ads}^- \rightarrow 3CO_2 + 3H_2O + 7e^-$	(9)
$CH_3CH_2OH + 60_{ads}^- \rightarrow 2CO_2 + 3H_2O + 6e^-$	(10)
$CH_3COCH_3 + 80_{ads}^- \rightarrow 3CO_2 + 3H_2O + 8e^-$	(11)

However, the layer-conductance chan_b with surface reactions, which forms the sensor signal as already described above, depends in a characteristic way on he particle size in relation to the width of the electron depletion layer influenced by the decoration of the particles with catalytically active nanoparticles as a second phase which form a composite. These aspects have been already very well introduced by Morrison [76]. If the average grain diameter of the MO is smaller than double the width of the electron depletion layer [26,70,77], the maximum sensitivity of the layer conductance on the surface chemical reactions can be expected. This grain size of maximum sensitivity is in the range of several nanometers [77]. On the other hand, those porous nanomaterials was speculated to be quite unstable under conditions of high operation temperature due to their high surface energy, which promotes post-sintering effects [7].

In this work, all the sensitivity tests have been conducted in gases extracted from the carrier gas probe immersed in aqueous sample, i.e., all gas atmospheres discussed are assumed to be more or less saturated by water at the given temperature condition of 18° C. This means, for interpretation of the sensing behavior of VOCs dissolved in water the understanding of the

chemisorbed on tin oxide surface, hydroxyl species are formed by molecular dissociation of water which acts as an electron donor [78,79]. This causes direct increase of the conductance (eq. 12).

$$H_2 0 + O_{ads}^- \rightarrow 20 H_{ads} + e^- \tag{12}$$

At dynamic operation of the chip-temperature (thermo-cyclic operation mode), as already mentioned above, non-steady state reaction conditions must be considered in particular. This means, according to the Langmuir adsorption model the fractional coverage of the reaction sites by adsorbed oxygen states as well as by target gas molecules depends considerably on the temperature of the gas sensitive layer and, of course, on the reaction kinetics depending on the local temperature and affected by diffusion effects. This parameter, which directly relates to the electronic conductance of the surface near region (electron depletion layer) [75], is now a variable of time. At isothermal operation to ose surface reactions represent a steady state. However, as investigated in [47], in thermo-cyclic mode, even at cycle-perie 1s beyond 15 min, this is never more correct. The fractional coverage of the adsorbed species depends not only on the actual temperature but also on the direction (positive or negative) of temperature change. This is well indicated by the un-symmetry of the CTPs visualized in. Fig. 14 and Fig. 15.

With regard to the CTP shape sampled from water saturated at mosphere (Go(hum air), Fig. 13), it is clearly illustrated, that the features representing the humidity are much more pronduced as peaks of the CTP from FSP-layers related to those of the SG-layers where typically only small deviations from the Go(a. rair)-plot (shoulders) are observed. This again may be interpreted as a hint that the very narrow distribution of the grain free of FSP-layers leads to much sharper CTP-features.

Not surprising is the fact, that in the same anb where characteristic CTP-features of the VOCs are observed, in most cases some characteristic deviations of the CTP/hu. air) from the corresponding curves at dry air (CTP(hum air) - CTP(dry air), observed as shoulders or peaks, are located (.ig. 15). According to eqs. 8-11, by reactions of VOCs with oxygen states in every case additional water is produced as a reaction product. This means, that the fractional coverage of water is increased which should enhance the formation of adsorbed hydroxyl species (eq. 13). However, as further demonstrated in Fig. 14, the very most CTP-features sampled from carboxylic acids are clearly larger than the corresponding Go-values. The opposite is the case for the very most CTPs sampled at ethanol and acetone exposure, although the gas phase concentrations are similar (Table 2). This is a very important difference which will be further discussed in a future paper, where analysis of such carboxylic acids in fermentation liquids in presence of other VOCs is emphasized.

Regarding the surface reaction processes with acetic and propionic acid, different possible reaction routes of carboxylic acids on tin oxide surfaces and reaction intermediates are described in the literature. It is well understood that at lower temperature the carboxylic acids dissociate on the metal oxide surface forming surface carboxylate [80–82], surface acetate and propionate. Surface carboxylate may undergo ketonization reaction [83,84] as reported for MgO [85], Al₂O₃ [84,86], TiO₂ [86],

ZrO₂ [

OH), as could be expected in presence of atmospheres with high water vapor partial pressure, seems to suppress the ketonization reaction [88] and formation of aldehyde - as confirmed by IR spectroscopy [88], was reported to prevail [89,90] and a Mars - Van Krevelen mechanism [90,91] has been postulated. The catalytic oxidation reactions of carboxylic acids at highly humid atmosphere were found to start at around 150 °C, forming aldehydes as intermediate products between 200-300 °C. In case of propionic acid in addition to formaldehyde also acetyldehyde formation was indicated before complete oxidation at round 300-350 °C takes place [89]. Similarly, the formation of ketene and acrolein from the surface acetate and propionate respectively by dehydration reaction was reported for ZnO [82] and TiO₂ [92,93].

Of course, much more surface analytical investigations would be necessary to correlate these specific reactions with the specific profile structures of the CTPs (Fig. 14 and Fig. 15) of the individual layers. For wever, by analyzing the features (reaction peaks) of the CTPs produced under well-defined atmospheric conditions, the interaction of acetic and propionic acid on thermo-cyclically operated SnO₂/additive layers seems to occur at the temperature range of 320-390 °C and 300-370 °C for acetic and propionic acid, respectively. This indicates similar underlying gas reactions in all the layers under investigation.

Typically, higher absolute G-Go values and pronounced gas splicific heatures on CTPs when exposed to propionic acid compared to acetic acid could be related to (i) different numbers e^{c} dectrons per molecule transferred to the conduction band by surface reaction with oxygen states (compare eq.9 win 10, and/or (ii) to the higher catalytic activity of tin oxide for propionic acid [47]. The measured overall conductance of a CTr and its profile structure reflects the specific gas reactions. In this context contributions from the grain surface, the grain bulk, the DE/MO interface and from the grain boundaries have to be considered [33]. The latter one is highly influenced by the brain size and the width of the sintered necks, which form the contacts between the grains [77].

The clearly higher pronounced (IPs features, and higher gas response observed for FSP-layers compared to SG-layers at exposure to carboxylic acids as well as to ethanol and acetone (Fig. 14-16) obviously is associated with its different morphology. Smaller average grain size and higher porosity of FSP-layers (Fig. 8 and Fig. 9) provide larger active surface area for gas reaction, as well as increased contribution of the depletion layer in relation to the bulk to the overall conductivity as already discussed above and in several studies [26]. Furthermore, it is assumed, that agglomerates from densely packed grains as observed in SnO₂(SG) layers (Fig. 10 and Fig. 11) provide smaller gas penetrability to the reaction sites at the interior of such agglomerates and therefore are less accessible for the gas reactions [94] resulting in reduced gas sensing.

In Fig. 15, which presents normalized CTP profiles, such gas specific features for acetic acid and propionic acid seem to be reduced with increasing gas concentration. This is somehow misleading. Since the data are normalized by the G-Go(hum air)value measured at maximum temperature of a cycle, at this representation the data indicate that the conductance change at the temperature maximum is relatively higher compared to the change at lower temperature.

ethanol undergoes dissociation by dehydration on acidic oxides forming ethene and water whereas on basic oxides forms acetaldehyde and hydrogen as surface intermediates by dehydrogenation process. Tin oxide is an amphoteric metal oxide [99]. This means that both reaction paths are possible, but the formation of acetaldehyde has been observed to be the thermodynamically more stable reaction product in a temperature range of 150-300 °C [95]. Having the clearly better enhanced individuality of the CTP shapes of FSP-layers in mind (Fig. 13), it is concluded that the surface reaction processes with ethanol seem to be more strongly occurring in SnO₂(FSP) and SnO₂(FSP)/additive composites compared to the corresponding sol-gel prepared layers. This means, that also these processes with ethanol are clearly better reflected in specific CTP-features observed at about 350-400 °C (Fig. 14 and Fig. 15). As already stated above, this aspect is of high relevance with respect to the chemical analysis capability enabled by numerical analysis of the CTPs [29].

Similar quality difference of CTPs is observed at acetone exposure. The interaction of acetone with adsorbed oxygen state (O⁻) on metal oxides , such as SnO₂ and ZnO are reported in [68–72]. At relatively higher temperature (\geq 300°C) acetone reacts with adsorbed oxygen states (O⁻) forming acetyl group, formaldehyde radical, methyl radical and CO in different reaction steps before forming CO₂. These reactions are represented as gas specific features for SnO₂(FSP) and SnO₂(FSP)/additive composites at ~300-315 °C as a shoulder (Fig. 15), whereas no specific reaction μ context are observed in case of SnO₂(SG) and SnO₂(SG)/additive composites.

Remarkably specific, individually structured CTP Chatures (Fig. 14-16), which are clearly different in shape when exposed to different analytes, were observed for all FSP-layers. B / comparison, the SG-layers generally show different CTP-features as well, but less pronounced and lower sensitivity (G-Gooochange vs. analyte concentration). The sensitivity enhancement due to smaller grain size of the FSP-layers was expected (son discussion above), but the enhanced specification of the CTP shape structures, which reflect the individual surface moleco lar reactions, was discovered by those comparative gas sensing experiments for the first time. The clearly better specificity of the normalized CTPs of the FSP-layers to all analytes under investigation in relation to the SG-layers is also illustrated in Fig. 15.

Another aspect is the relative sensitivity of the layers. As illustrated in Fig. 14, in nearly all cases, the FSP-layer shows the higher CTP-maximum related to the corresponding SG-layer for all analytes exposed. As already stated above, this is not surprising, because the extremely fine FSP-powders and correspondingly highly porous FSP-layers show an extremely large MO-surface, and it can be assumed that the conductance change affects more or less the whole grain volume because the grain diameter is in the range of double the Debye length of the electron depletion layer. This interpretation is also supported by the CTPs plotted in Fig. 13, which illustrate the difference of the CTP(hum air) related to the CTP(dry air). These differences of the FSP-layers are observed formidably bigger in relation to those of the SG-layers. In this context, it is a matter of fact, that the

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generally thinner (Fig. 7).

Coming back to the CTP-shape structures of the FSP-layers, with regard to the desired capability to analyze the formation of carboxylic acids in fermentation processes well discriminated to other gas components by numerical analysis of such CTPfeatures [29], the differences of the CTP-shapes related to acetic and propionic acid vs. ethanol and acetone are mostly pronounced by the SnO₂(FSP)/NASICON - and the SnO₂(FSP)/Al₂O₃-layer. It seems that the surface reactions of acetic and propionic acid are catalyzed by the presence of NASICON as already described in [30]. Much higher sensitivities of SnO₂/NASICON-layers in relation to pure SnO₂-layers and clearly different CTP-shapes were explained by a model of (i) specific e⁻ $-Na^+$ interaction at the SnO₂/NASICON interface which was assumed to amplify the sensing behavior compared to pure tin oxide [30] and (ii) the catalytic properties of NASICON which may enhance the form tion of intermediate products and spillover to O^{2^-} surface states at the neighboring SnO₂ grains where they are complete v ox dized taking additional influence on the surface depletion layer [100].

The enhanced sensitivity properties of the SnO₂(FSP)/Alumina-lay r, n ay be explained by the existence of Lewis acid sites provided by the alumina, which may influence the dehydration and cracking of the organic molecules [101,102] promoting intermediate products. The combination of these catalytic Jro_{p} or Jes of alumina with surface processes involving those intermediate products and O²⁻ surface states at very fir \circ Sr J₂(FSP) grains, as discussed above, may result in pronounced CTP features (Fig. 14 and Fig. 15) and also in improved gas (\circ sponse (Fig. 18).

In relation to SnO₂(FSP)/NASICON, the SnO₂, F[•]P) YSZ-layer shows clearly lower response to acetic acid, ethanol, and acetone but it is highest for propionic acid. YS[•]2. known for its oxygen ion conductivity and its catalytic properties for oxidation reactions [103]. This means, similar to the e⁻ –Na⁺ interaction in SnO₂/NASICON composites an e⁻ – O²⁻ - interaction over the SnO₂/YSZ-grain boundaries may be resumably assumed here, which could lead to a similar amplification of the sensing behavior of individual carboxylic acids as already discussed for the NASICON additive. Indeed, this enhanced sensitivity of the SnO₂(FSP)/YSZ-composite to carboxylic acids was found in [30] as well. However, in this work the relative sensor response amplification vs. the pure SnO₂(FSP)-layer was found to be not significant (Fig. 18). This may be hypothetically explained by the lower O²⁻-mobility in YSZ and, of course, the effects of e⁻ - anion (SnO₂/NASICON)-layers. Nevertheless, the CTP features observed for SnO₂(FSP)/YSZ are somewhat enhanced as well and show some similarities with those of the SnO₂(FSP)/Al₂O₃-layer. This suggests that the decoration of SnO₂(FSP) with YSZ does not induce other additional surface reactions, but the corresponding CTP-features may be shifted due to different catalytic conditions.

Finally, a general overview about the differences in sensitivity is achieved by a closer look to the power-law exponents (β) and pre-exponential factors (α), as defined by eq. 2 and summarized in table 3. As exemplary illustrated in Fig. 17, the enhanced

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the differences in morphology, as already discussed above. An exception is the $SnO_2/NASICON$ -layer. In case of acetic acid exposure, the pre-factor α is highest of the group of SG-layers and the lowest of the group of FSP-layers. Hence, at propionic acid exposure the α -value fitted for the $SnO_2/NASICON$ -layers is the largest in both groups of preparation (Table 3), however, the exponential values β are the lowest in each group. This is illustrated by the Σ G-Go - plots in Fig. 17b. In relation to the other $SnO_2/additive$ -layers the $SnO_2(FSP)/NASICON$ -layer attracts attention by a sharp increase of response at propionic acid concentrations below 250 ppm and a markedly lower further increase of response at concentrations beyond. This specific response behavior of the $SnO_2(FSP)/NASICON$ -layer may give an additional hint to the special conditions of gas response of this composite as already discussed above.

6 Conclusions and Outlook

The experiments have impressively shown that SnO₂/additive gas service 'ayers with SnO₂-powder prepared by flame spray pyrolysis (FSP) technique provide considerably better sensitivity in all target gases tested compared to those SnO₂/additive-layers with SnO₂-powder prepared by sol-gel technique. Tri. is the case, although a very fine sub-structure of the sol-gel prepared SnO₂-grains is in a similar range of the grain siz or prepared by FSP-technique. Surprisingly, there is not only better sensitivity but also more enhanced specificity of t¹.e i TP-1 atures of FSP-prepared SnO₂/additive-layers vs. SG-prepared SnO₂/additive-layers observed when the sensors are thern. p-cyclically operated. This was interpreted as the result of the different SnO₂-morphologies consisting of fine grain mitworks with high porosity, as provided by the FSP-layers in relation to the SG-prepared layers. It is well known that the FS 2-la, ors provide highly active surface areas for gas reactions, which seem to be one of the key factors favoring target gas - notal oxide - interactions which ultimately result in enhanced gas specific CTPfeatures. This is highlighted in clearly difference, very distinctive CTP-features extracted from the layers related to exposures of acetic or propionic acid and, even nor the important for analysis, in relation to ethanol and acetone. Furthermore, a characteristic influence of the additives (alumina, YSZ, NASICON(x=2)) on the CTP-features could be disclosed, respectively.

More detailed comparison of the CTP-features achieved by the additives under study revealed remarkable differences in CTP-shapes. This may be a result of specific electron – mobile ion interactions across the common SnO₂/additive – interface when the additive is a solid electrolyte like YSZ or NASICON, as already reported in an earlier study. It is supposed that those interactions may take influence on the target gas reactions with the oxygen surface states. The authors are assured, that such enhanced sensitivities to specific gas components and the specificities of the corresponding CTP-features gained by additives, as observed in these studies, could be even more enhanced, if the additive powders could be prepared with grain sizes similar to those of the SnO₂-grains as prepared by the FSP-technique.

acetic and propionic acid, make the SnO₂(FSP)/additive-layers (additives: alumina, YSZ, NASICON) very promising candidates for monitoring of carboxylic acid development in different processes like e.g., biogas fermentation. In a further step, it is of high interest to investigate how the CTPs of the carboxylic acids are influenced by the presence of other simultaneously developed VOCs in such processes. These aspects have been investigated as well and will be reported in an upcoming publication.

CRediT authorship contribution statement

Binayak Ojha: Methodology, Investigation, Formal Analysis, Software, Visualization, Data Curation, Writing-Original Draft, Writing-Review & Editing. **Margarita Aleksandrova:** Investigation, Formal Analysis. **Matthias Schwotzer:** Investigation, Formal Analysis. **Matthias Franzreb:** Writing-Review & Editing. **Heinz Kohler:** Conceptualization, Methodology, Writing-Original Draft, Writing-Review & Editing, Supervision, Project Administration, Funding acquisition

Declaration of Competing Interest

The authors report no declarations of interest.

Acknowledgements

We are deeply grateful to Prof. Dr. Andreas Güntner, Dept. on Machanical and Process Engineering, ETH Zürich (CH). for providing the FSP-prepared SnO₂ powder. This work is part of the EBIPREP collaboration project (www.ebiprep.eu) financed by the EU International Programme INTERREG V Oberrheim 2017-2020.

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Fig. 1. Sensor operation methodology. (a) Applied heater voltage over one temperature cycle (black) and corresponding temperature sensor resistance (blue). (b) Temperature vs. time (after calibration of the Pt-meander) and simultaneously measured CTP of one of the layers $(SnO_2(FSP)/1\%Pd)$ at acetic acid exposure (red).



Fig. 2. XRD diffractograms (Rigaku Miniflex 600, Cu K-alpha) of SnO₂ powder prepared by a sol-gel route and calcinated at different temperatures (80 °C and 450 °C). The diffraction peaks are indicated in accordance with the rutile structure of SnO₂ [33].



Fig. 3. XRD diffractograms of NASICON (x=2) powder sintered at different temperatures (800 °C, 900 °C and 1000 °C). The small reflections marked by green dots indicate a small amount of Zirconia as a second phase.



Fig. 4. Sensor chip preparation and housing. (a) Schematic illustration of different componer $a \leq a$ -fold sensor chip in exploded view. (b) Glass passivated Pt-heater structure with contact pads on the reverse side of the sensor chi, $a \leq a$ -fold sensor chip different SnO₂(SG) layers with different thickness. (d) Sensor chip deposited with SnO₂(FSP)/additive layers $a \in a$ -fold sensor chip with IDEs covered by SnO₂(SG)/additive layers. (f) 4-fold sensor array chip mounted on a TO-8 header.



Fig. 5. Schematic representation of the setup for analysis of dissolved VOC by a combination of a carrier gas probe with two MOG sensor arraychips.



Fig. 6. CTPs of $SnO_2(FSP)/1\%Pd$ when exposed to (a) 4% acetic acid at different carrier gas j ow rule and (b) 2000 ppm acetic acid at different cycle time.

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Fig. 7. Topographic images and line thickness profiles of (a) $SnO_2(SG)$ layers with different thickness (b) $SnO_2(FSP)$ /additive layers and (c) $SnO_2(SG)$ /additive layers



Fig. 8. ESEM images of different SnO₂(FSP)/additive gas sensitive layers. (a) SnO₂(FSF $_1$ ($_L$, $\subseteq J_2$ (FSP)/Alumina (c) SnO₂(FSP)/YSZ and (d) SnO₂(FSP)/NASICON



Fig. 9. ESEM images recorded using backward scattered electron analysis and corresponding spectra of EDS point analysis taken at different areas as indicated in the photographs, respectively. (a) SnO₂(FSP)/Alumina (b) SnO₂(FSP)/YSZ and (c) SnO₂(FSP)/NASICON



Fig. 10. ESEM images of different SnO₂(SG)/additive gas sensitive layers. (a) SnO₂(SG` (L; SnC₂(SG)/Alumina (c) SnO₂(SG)/YSZ and (d) SnO₂(SG)/NASICON



Fig. 11. ESEM images recorded using backward scattered electron analysis technique and corresponding spectra of EDS point analysis taken at different areas as indicated in the photographs, respectively. (a) SnO₂(SG)/Alumina (b) SnO₂(SG)/YSZ and (c) SnO₂(SG)/NASICON



Fig. 12. Response of SnO₂(SG) layers with different thickness (5 μ m, 9.4 μ m, and 18.2 μ m) on ϵ osure to 2000 ppm acetic acid dissolved in DI water at pH 3. (a) Absolute CTPs, (b) Normalized response and (c) Absolute CTP-integrals vs. *layer* sciences.



Fig. 13. Conductance over time profiles (CTPs) of eight dif, 21 int sensitive layers measured for dry synthetic air (Go(dry air) and for humidified air (Go(hum air)) as extracted by the carrier gas probe an Pl water at pH 7 prior to the exposure to model VOCs.



Fig. 14. Complete sensor responses in the matrix form: Conductance over time profiles (CTP) of eight different sensitive layers (in columns) measured for various concentration of different VOCs (in rows).



Fig. 15. Normalized G-Go plots in the matrix form: Conductance over time profiles (CTP) of eight different sensitive layers (in rows) measured for various concentration of different VOCs (in columns). In addition, for every layer the influence of humidity on the base line (Go(dry air)) is illustrated as well as Go(hum air)-Go (dry air) normalized plot. The humidity is related to gas saturation at a water temperature of 18 °C.



Fig. 16. Gas specific CTP features of (a) SnO₂(FSP), (b) SnO₂(FSP)/Alumina, (c) SnO₂(FSP)/YSZ, (d) SnO₂(FSP)/NASICON, (e) SnO₂(SG), (f) SnO₂(SG)/Alumina, (g) SnO₂(SG)/YSZ, (h) SnO₂(SG)/NASICON on exposure to 1000 ppm acetic acid, 1000 ppm propionic acid, 30 ppm ethanol, and 5 ppm acetone dissolved in DI water at pH 3.



Fig. 17. Absolute sensor response \sum (G-Go) of a) SnO₂(SG)/Alumina – lay $2r \sqrt{d} nO_2$ (FSP)/Alumina – layer vs. concentration of acetic acid and b) of several layers vs. concentration of propionic acid.



Fig. 18. Comparison of relative sensor response S (eq. 3) of different $SnO_2(SG)$ and $SnO_2(FSP)$ composites at exposure to different VOCs dissolved in water at pH 3.

Binayak Ojha: Methodology, Investigation, Formal Analysis, Software, Visualization, Data Curation, Writing-Original Draft, Writing-Review & Editing. **Margarita Aleksandrova:** Investigation, Formal Analysis. **Matthias Schwotzer:** Investigation, Formal Analysis. **Matthias Franzreb:** Writing-Review & Editing. **Heinz Kohler:** Conceptualization, Methodology, Writing-Original Draft, Writing-Review & Editing, Supervision, Project Administration, Funding acquisition

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The authors declare the following financial interests/personal relationships which may be considered as potential competing interests:

Decla